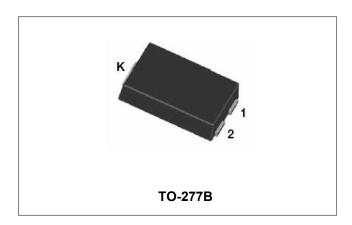


# Technical Data Data Sheet N1709 Rev. A

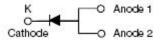




## ST1060S SCHOTTKY RECTIFIER



### **Circuit Diagram**



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Ultra low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	60	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =80°C, rectangular wave form	10	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	275	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 10A, Pulse, T <sub>J</sub> = 25 °C	-	0.60	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	-	0.36	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	20	-	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C$ $f_{SIG} = 1MHz$	850	-	pF

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%



# Technical Data Data Sheet N1709 Rev. A





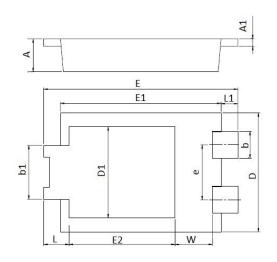
## **Thermal-Mechanical Specifications:**

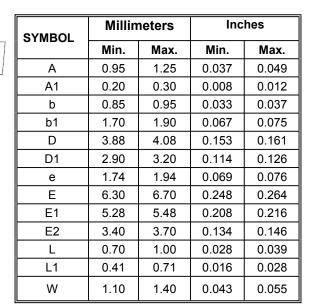
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient (Note 2)	$R_{ heta JA}$	DC operation	110	°C/W
Typical Thermal Resistance Junction to Case (Note1)	R <sub>0</sub> JC	DC operation	10	°C/W
Approximate Weight	wt	-	0.08	g

Notes: 1. Mounted on an FR4 PCB, single-sided copper, with 100cm<sub>2</sub> copper pad area.

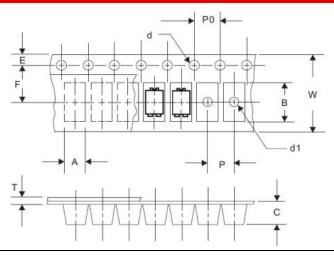
2. Mounted on an FR4 PCB, single-sided copper, mini pad.

#### **Mechanical Dimensions TO-277B**





## **Carrier Tape Specification TO-277B**



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
Е	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

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## Technical Data Data Sheet N1709 Rev. A



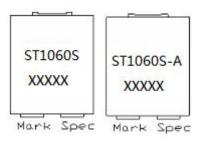


### **Ordering Information**

Device	Package	Shipping	
ST1060S	TO-277B(Pb-Free)	5000pcs/ reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

#### **Marking Diagram**



Where XXXXX is YYWWL

 ST
 = Device Type

 10
 = Forward Current (10A)

 60
 = Reverse Voltage (60V)

 S
 = Package type

 -A
 = AEC-Q101

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

#### DISCLAIMER:

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- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
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